Different Realizations of Ionization Trackers



Drift Chamber Cell



Fig. 11. Cell structure of large area drift chamber [MA 77].

- Carefully shape potential (field lines)
- Optimize drift time space relation





Left-Right Ambiguity Resolution



Jet Chamber



e^+e^- annihilation at 30 GeV

Lorentz Angle – Drift Chamber in Magnetic Field

• Drifting electron will see Electric Field \overline{E} Magnetic Field \overline{B}

 $m\dot{\overline{v}} = q\left(\overline{E} + \overline{v} \times \overline{B}\right)$

 Will also see stochastic force due to collisions with gas molecules

$$m\dot{\overline{v}} = q\left(\overline{E} + \overline{v} \times \overline{B}\right) + mA(t)$$

Assume over time

 $\overline{E}, \overline{B} =$ stochastic acceleration retardation

constant v_D

$$\dot{\overline{v}}_{D} = \mathbf{0} = \frac{q\overline{E}}{m} + \left(\overline{v}_{D} \times \frac{q\overline{B}}{m}\right) - \left\langle A(t) \right\rangle$$

 $A(t) \rightarrow \frac{v_D}{\tau}$ mean time between collisions

$$\frac{\overline{v}_D}{\tau} - \left(\overline{v}_D \times \frac{q\overline{B}}{m}\right) = \frac{q\overline{E}}{m}$$





Lorentz Angle – Drift Chamber in Magnetic Field

solution:

$$\overline{v}_{D} = \frac{\mu}{1 + \omega^{2} \tau^{2}} \left(\overline{E} + \frac{\overline{E} \times \overline{B}}{B} \omega \tau + \frac{(\overline{E} \cdot \overline{B}) \cdot \overline{B}}{B^{2}} \omega^{2} \tau^{2} \right)$$

Drift velocity has three components

(1) parallel to \overline{E} (2) parallel to \overline{B} (3) perp to plane of $\overline{E}, \overline{B}$

• If $\overline{E}, \overline{B}$ perpendicular $\overline{E} = (E_x, 0, 0)$ $\overline{B} = (0, 0, B_y)$

$$v_{x} = \mu E_{x} \frac{1}{1 + \omega^{2} \tau^{2}} \qquad \tan \alpha = \omega \tau = \frac{v_{y}}{v_{x}}$$

$$v_{y} = -\mu E_{x} \frac{\omega \tau}{1 + \omega^{2} \tau^{2}} \qquad \Longrightarrow \qquad \tan \alpha = \omega \tau = \frac{q\overline{B}}{m} \frac{m\mu}{q} = \mu B = \frac{v_{D}}{E} B$$

$$v_{z} = 0$$

LORENTZ ANGLE



N

ELECTRIC FIELD DIRECTION

$$\tan \alpha = \frac{v_D}{E} B$$



Structure of ZEUS DC



Tilted E Field – R-L ambiguity resolution Zeus CTD Event Display



Spatial Resolution



Stereo Wires – 3-d Reconstruction







R.S. Orr 2009 TRIUMF Summer Institute



10



- 1

Square Drift Cells - ARGUS



- Potential Wires
 - Precision
 - High Density of Information
 - Pattern recognition complex ⇒

R-L ambiguity resolved by trying all possible combinations



dE/dx Particle Identification



BaBar Drift Chamber



constructed at TRIUMF

Belle II



The Belle 2 detector **Barrel KLM** Endcap Endcap KLM KLM Solenoid -1 PID PXD Endcap SVD CDC ECI Ó 1 2 3 4 (m)

CDC in pictures



CDC and CDC wires

CDC is composed of:

• 9 super layers which consist of

- 56 layers (grouped to 1x8 and 8x6)
- 14336 wires (160 384 wires in a layer).



An example typical event of $\Upsilon(4S)$ decay (no beam background)



dE/dx measurements and PID

Ionisation is \sim distance traversed, so charge/distance is used:

- Charge in each layer summed.
- Distance approximated as straight line to next layer.



dE/dx - extracted as avg ionisation:





electrons, muons, pions, kaons, protons. \rightarrow PID possible by comparing with distributions. & combining with dE/dx from PXD/SVD.



Time Projection Chamber

• Only two drift cells

• \overline{E} parallel to \overline{B} , so no Lorentz angle



 Good pattern recognition and precision space charge limitation in medium multiplicity environment



Diffusion in TPC



Diffusion in TPC



SPACE CHARGE LIMITATIONS

HEAVY IONS PRODUCED BY GAS AMPLIFICATION -> DISTORT ELECTRIC FIELD

USE GATED GRID -> ONLY ALLOW ELECTRONS IN TO AMPLIFICATION REGION FOR GOOD TRIGGERS

Closed gate



С



ALICE TPC -> HIGH MULTIPLICITY GOOD PATTERN RECOGNIZION -> LOW RADE



ATLAS Tracker





Straw tracker test beam module







Inner Detector (ID)

The Inner Detector (ID) comprises four sub-systems:

•Pixels (0.8 10⁸ channels)

•Silicon Tracker (SCT) (6 10⁶ channels)

•Transition Radiation Tracker (TRT) (4 10⁵ channels)

•Common ID items





Microstrip gas chambers



CHARGE BUILD UP ON MICROSTRIPS

- THE SUBSTRATE ON MICROSTRIPS HAS A HIGH RESISTANCE
- IN VERY HIGH RATE ENVIRONMENT
- -> CHARGE BUILD UP
 - -> DISCHARGE
 - -> DAMAGE



GEM: The Gas Electron Multiplier

(R. Bouclier et al., NIM A 396 (1997) 50)





GAS AMPLIFICATION DECOUPLED FROM READ OUT REGION -> HIGH RATE - NO SPACE CHARE -> NO BREAKDOWN BECAUSE IONS DO NOT PENETRATE GEM FOIL CAN CASCADE FOILS TO GET LARGE ENDUGH GAIN $\sim 10^4$

MICRO MEGA







